

Timepix detector operation at CERN accelerator facilities



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on behalf of the UA9 Collaboration**

Abstract We describe the main performances for the Timepix silicon detector operation at the SPS and H8 extracted beam line at CERN. The main calibration results of the detector and an improved cluster analysis algorithm are presented as well. In the present work we are introducing the main functionality of the device and its limitation for the measurement of the high-energy particles flux.

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** https://ua9.web.cern.ch/sites/ua9.web.cern.ch/files/UA9_Experiment_author_list.pdf









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UA9 collaboration



UA9 collaboration. Bent crystal physics

Channeling is the retention between crystalline planes:

- → Charged particles
- \rightarrow Momentum is nearly parallel to the atomic planes of the crystal

 \rightarrow Transverse kinetic energy not exceeding the depth Uo of the crystal potential.



Using of the secondary curvature of the crystal to guide the particles



Deflecting Angle of Protons after passing the crystal vs Crystal Rotation Angle

UA9 collaboration. Applications

Beam collimation

$\hfill\square$ $\hfill\square$ The halo particles are removed by a cascade of amorphous targets:

- 1. Primary and secondary collimators intercept the diffusive primary halo.
- Particles are repeatedly deflected by Multiple Coulomb Scattering also producing hadronic showers that is the secondary halo
- 3. Particles are finally stopped in the absorber
- 4. Masks protect the sensitive devices from tertiary halo



Measuring of short living baryons MDM (e.g. $\Lambda c^{+}[udc]$)

$$\Theta_{\mu} = \gamma \left(rac{g}{2} - 1 - rac{g}{2\gamma^2} + rac{1}{\gamma}
ight) \Theta pprox \gamma \left(rac{g}{2} - 1
ight) \Theta$$



DOI: 10.1007/JHEP08(2017)120

Bent crystals work as a "smart deflectors" on primary halo particles

• Coherent particle-crystal interactions impart large deflection angle that minimize the escaping particle rate and improve the collimation efficiency







https://arxiv.org/pdf/1707.05151.pdf

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Timepix & Timepix3



Timepix. Hardware description

Timepix:

- \rightarrow a **hybrid** pixel detector;
- \rightarrow 300 µm thick Silicon layer;
- \rightarrow **14×14 mm**² bump bonded read-out chip;
- \rightarrow a matrix formed by **256×256 pixels;**
- → each pixel is 55×55 μ m²;
- \rightarrow maximum digital counter is **11810** (**13.5 bit**);
- \rightarrow Clock 96 MHz (~10.4 ns).

Modes of the detector operation:

- Medipix mode
- Time of Arrival (ToA) mode
- Time over Threshold (ToT) mode

Readout: USB2.0 via FITPix, with a frame rate up to 90 frames/s

Timepix





Timepix3:

- → a **hybrid** pixel detector;
- → Silicon/Carbon layer;
- → 14×14 mm² bump bonded read-out chip;
- \rightarrow a matrix formed by **256**×**256 pixels**;
- → each pixel is **55×55 \mum²**;
- → Clock 40 MHz (25.0 ns) + 640 MHz fast Clock (1.56 ns)

Each Timepix pixel can work in one of three modes:

- ToA+ToT mode (ToA 18 bit & ToT 10 bit)
- ToA mode (ToA 18 bit)
- Event count & Integral ToT (iToT 18 bit & eCount 10 bit)

Readout: Katherine, Ethernet embedded readout interface, 15 Mhits/s

Timepix3



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Pixelman: Timepix + FITPix



(1) **Pixelman Graphical User Interface** (GUI) (allows to visualize the acquired frames and to write data into the text files);

(2) **Python scripting plugin** (gives a possibility to integrate Pixelman libraries inside other data acquisition (DAQ) systems; multiple device synchronization).

http://aladdin.utef.cvut.cz/ofat/others/Pixelman/Pixelman.html

Burdaman: Timepix3 + Katherine



Allows detector control and data acquisition. Supports more readout devices connected to the Ethernet network.

https://doi.org/10.1088/1748-0221/12/11/C11001

Timepix applications in UA9



Timepix applications. Experimental areas



H8 (UA9 test-beam): Xe & Ar ions 70 & 150 GeV/u, protons 400 GeV/c and pions 180 GeV/c – up to 10⁶ particles/s **SPS (UA9 MD):** protons 270 GeV/c – single bunch ~10¹¹ p, beam on COAST, extracted by the crystal ~10⁵ particles/s

Timepix applications. H8 test-beam



*http://iopscience.iop.org/article/10.1088/1748-0221/6/04/P04006/meta

Timepix3 (Diamondpix) Placed ~10 m from the crystal 400 GeV/c protons



Quadpix (4 Timepix chips) Placed ~50 m from the crystal 400 GeV/c protons



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Timepix applications. H8 test-beam

Integrated 500 frames (1 sec each) in MPX mode



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Timepix applications. Cluster analysis



 → In ToA mode we take only the first hit of the pixel
 → Overlapping of the clusters



Comparison between the standard Cluster Analysis (CA) and improved one



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256

Timepix applications. Telescope and Double channeling



The telescope provides very good 70 µrad angular resolution for reconstructed particle tracks with a flight base of 1.2 m and track reconstruction efficiency of about 10 %.





*The setup is located inside SPS beampipe.

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The measured flux of the particles for H8 is about **0.6**•**10**⁵ **pions/s** 180 GeV/c (276 pions/($s \cdot mm^2$) in the beam core) and for SPS is about **1.2**•**10**⁵ **protons/s** 270 GeV/c (2606 protons/($s \cdot mm^2$) in the beam core), done with the Timepix detector (the active area is 196 mm²).



The image of the pion 180 GeV/c beam at H8 SPS extracted beam line.

The image of the proton 270 GeV/c beam at SPS, deflected by the crystal.

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The Timepix is a very user friendly device that seems to be robust enough to be used also in quantified beam monitoring also in secondary vacuum inside beam pipes (three years of operation, up to 0.4 kGy/year at SPS LSS5) of the accelerator machine like SPS at CERN.

Backup slide. Timepix Technical specifications

Features:

Pixel size 55µm x 55µm 256 x 256 pixels Single energy threshold (adjustable per pixel with 4 bits) Three modes of operation: (1) single particle counting (2) Time over Threshold (TOT) and (3) Time of Arrival (TOA) Electron or hole collection -> compatible with various sensor materials Can be combined with Gas Gain Grid to readout electron deposition in a gas detector 3-side buttable

Applications:

Adaptive optics and other visible or near visible light applications Astrophysics Background radiation monitoring Digital Autoradiography Dosimetry Education Electron microscopy Life Sciences Neutron imaging Various X-ray and gamma-ray imaging applications X-ray polarimetry measurements

https://medipix.web.cern.ch/collaboration/medipix2-collaboration

| General | |
|---|---|
| Parameter | Value |
| CMOS technology | 0.25 um |
| Pixel matrix | 256 x 256 |
| Pixel size | 55 um x 55 um |
| Design | CERN |
| Features | Single energy threshold (adjustable per pixel with 4 bits) Three modes of operation: (1) single particle counting (2) Time over Threshold (TOT) and (3) Time of Arrival (TOA) Can be combined with Gas Gain Grid to readout electron deposition in a gas detector Hit rate 100 KHz |
| | HIT rate 100 KHz |
| Power supply | 3-side buttable Two independent 2.2V power supplies for the analog and digital part |
| Number of transistors | ~36 million |
| Analog front end (pixel cell) | |
| Parameter | Value |
| Baseline shift preamplifier output | 112 e- rms |
| Signal polarity | Positive and negative |
| Detector capacitance | |
| Leakage current | -10 to 20 nA |
| TOT monotonicity | Up to 200Ke- |
| Time to peak | 110 ns |
| Noise | 75 e- |
| Analog static power comsumption | 6 uW |
| Analog power comsumption | 440mW |
| Digital part (pixe | l cell + periphery) |
| 1 counter/shift register | 14 bits (11810 counts) |
| periphery | 13 8-bit DACs to set voltages in the chip 1 256-bit Fast Shift Register to write in or readout the sensitive area 127 I/O pads LVDS drivers and receivers (configuration of the chip in serial mode) Parallel 32-bit CMOS bus (chip readout can be serial or parallel) |
| Readout time in serial mode (100 MHz clock) | 9 ms (102 Mbps) |
| Readout time in parallel mode (100 MHz clock) | 266 us (3.5 Gbps) |
| Digital power comsumption | 450mW |

Features:

Pixel size 55µm x 55µm 256 x 256 pixels Timepix3 is suitable for readout of both semiconductor detectors and gas-filled detectors Single thresholds per pixel each with 4 bits of local adjustment Two main measurement modes: (1) simultaneous 10 bit ToT and 18 bit TOA and (2) 10 bit event counting and 14 bit integral TOT TOT monotonic for large positive charges Fast TOA for time stamping with a precision of 1.56 ns Data driven readout: dead time free, for a maximum hit rate of 40 Mhits/s/cm^2 Shutdown/wake-up features for power pulsing tests on a full system 3-side buttable (with a single 1.2mm dead edge) TSV ready

Applications:

X-rays imaging

Particle track reconstruction.

Timepix3 is suitable for readout of both semiconductor detectors and gas-filled detectors.

| Gene | eral realures |
|---------------------------------|--|
| Parameter | Value |
| CMOS technology | 0.13 um |
| Pixel matrix | 256 x 256 |
| Pixel size | 55 um x 55 um |
| Design | CERN, NIKHEF, Bonn University |
| Features | Two main measurement modes: (1) simultaneous 10 bit ToT and 18 bit TOA and (2) 10 bit event counting and 14 bit integral TOT TOT monotonic for large positive charges Fast TOA for time stamping with a precision of 1.56 ns Data driven readout: dead time free, for a maximum hit rate of 40 Mhits/s/cm^2 Shutdown/wake-up features for power pulsing tests on a full system |
| Power supply | |
| Number of transistors | |
| Anal | og Front end |
| Parameter | Value |
| Baseline Preamplifier output | |
| Signal polarity | Positive and negative |
| Detector capacitance | 25 to 100 fF |
| Leakage current | -5 to 20 nA |
| TOT monotonicity | Up to 300Kh+ |
| TOA jitter and mismatch | Compatible with 1.56ns resolution (gas detector applications) |
| Time to peak | 25 ns (in view of VELOpix) |
| Noise + threshold mismatch | 90e- |
| Equalization DACs | 4 bit (compensate pixel to pixel threshold mismatch) |
| Analog static power consumption | 12 uW/pixel |

https://medipix.web.cern.ch/collaboration/medipix3-collaboration